



# PJD25N03

## 30V N-Channel Enhancement Mode MOSFET

**Voltage**

**30 V**

**Current**

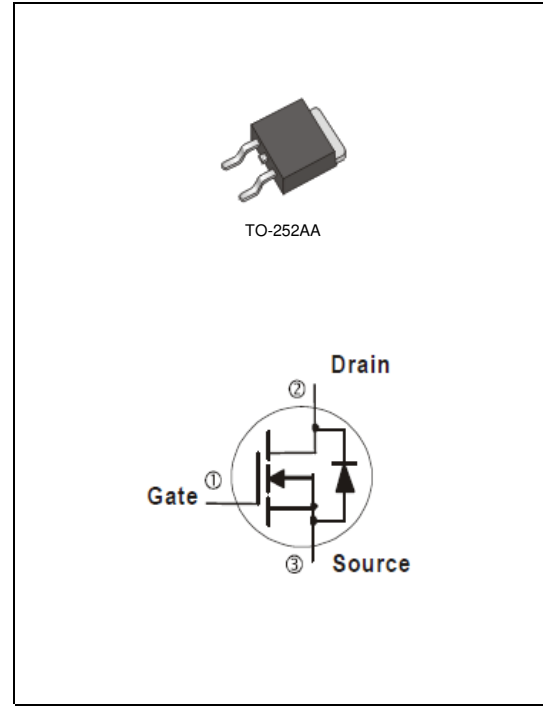
**25 A**

### Features

- $R_{DS(ON)}$ ,  $V_{GS}@10V, I_D@12A < 25m\Omega$
- $R_{DS(ON)}$ ,  $V_{GS}@4.5V, I_D@6A < 33m\Omega$
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS2.0 (2011/65/EU & 2015/865/EU directive)
- Green molding compound as per IEC61249 Std.. (Halogen Free)

### Mechanical Data

- Case : TO-252AA Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Weight : 0.0104 ounces, 0.297grams



## Maximum Ratings and Thermal Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		$V_{DS}$	30	V
Gate-Source Voltage		$V_{GS}$	$\pm 20$	V
Continuous Drain Current	$T_C=25^\circ\text{C}$	$I_D$	25	A
	$T_C=100^\circ\text{C}$		16	
Pulsed Drain Current <sup>(Note 1)</sup>	$T_C=25^\circ\text{C}$	$I_{DM}$	100	
Power Dissipation	$T_C=25^\circ\text{C}$	$P_D$	25	W
	$T_C=100^\circ\text{C}$		10	
Continuous Drain Current	$T_A=25^\circ\text{C}$	$I_D$	7.0	A
	$T_A=70^\circ\text{C}$		5.6	
Power Dissipation	$T_A=25^\circ\text{C}$	$P_D$	2.0	W
Power Dissipation	$T_A=70^\circ\text{C}$		1.3	
Single Pulse Avalanche Energy <sup>(Note 6)</sup>		$E_{AS}$	32	mJ
Operating Junction and Storage Temperature Range		$T_J, T_{STG}$	-55~150	$^\circ\text{C}$
Typical Thermal Resistance <sup>(Note 4,5)</sup>	Junction to Case	$R_{\theta JC}$	5.0	$^\circ\text{C/W}$
	Junction to Ambient	$R_{\theta JA}$	62.5	

- Limited only By Maximum Junction Temperature



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## Electrical Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
<b>Static</b>						
Drain-Source Breakdown Voltage	$BV_{DSS}$	$V_{GS}=0V, I_D=250\mu A$	30	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	1.2	1.7	2.5	
Drain-Source On-State Resistance	$R_{DS(on)}$	$V_{GS}=10V, I_D=12A$	-	21	25	mΩ
		$V_{GS}=4.5V, I_D=6A$	-	26	33	
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=30V, V_{GS}=0V$	-	-	1.0	μA
Gate-Source Leakage Current	$I_{GSS}$	$V_{GS}=\pm 20V, V_{DS}=0V$	-	-	$\pm 100$	nA
<b>Dynamic</b> (Note 7)						
Total Gate Charge	$Q_g$	$V_{DS}=15V, I_D=8A,$ $V_{GS}=4.5V$ (Note 2,3)	-	4.3	-	nC
Gate-Source Charge	$Q_{gs}$		-	1.3	-	
Gate-Drain Charge	$Q_{gd}$		-	1.6	-	
Input Capacitance	$C_{iss}$	$V_{DS}=25V, V_{GS}=0V,$ $f=1.0\text{MHz}$	-	392	-	pF
Output Capacitance	$C_{oss}$		-	76	-	
Reverse Transfer Capacitance	$C_{rss}$		-	54	-	
Turn-On Delay Time	$t_{d(on)}$	$V_{DS}=15V, I_D=1A,$ $V_{GS}=10V, R_G=6\Omega$ (Note 2,3)	-	5.9	-	ns
Turn-On Rise Time	$t_r$		-	11	-	
Turn-Off Delay Time	$t_{d(off)}$		-	17	-	
Turn-Off Fall Time	$t_f$		-	3.8	-	
<b>Drain-Source Diode</b>						
Maximum Continuous Drain-Source Diode Forward Current	$I_S$	---	-	-	25	A
Diode Forward Voltage	$V_{SD}$	$I_S=1A, V_{GS}=0V$	-	0.73	1.0	V

**NOTES :**

1. Pulse width  $\leq 300\mu s$ , Duty cycle  $\leq 2\%$
2. Essentially independent of operating temperature typical characteristics.
3. Repetitive rating, pulse width limited by junction temperature  $T_{J(MAX)}=150^\circ\text{C}$ . Ratings are based on low frequency and duty cycles to keep initial  $T_J=25^\circ\text{C}$ .
4. The maximum current rating is package limited.
5.  $R_{\theta JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch<sup>2</sup> with 2oz. square pad of copper.
6. The test condition is  $L=1\text{mH}, I_{AS}=8A, V_{DD}=25V, V_{GS}=10V$
7. Guaranteed by design, not subject to production testing.



# PJD25N03

## TYPICAL CHARACTERISTIC CURVES

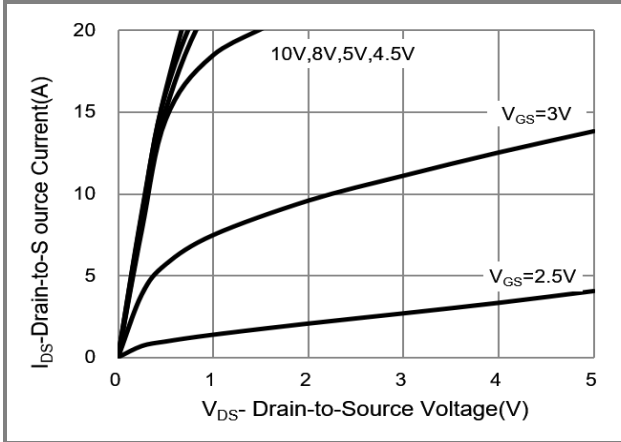


Fig.1 Output Characteristics

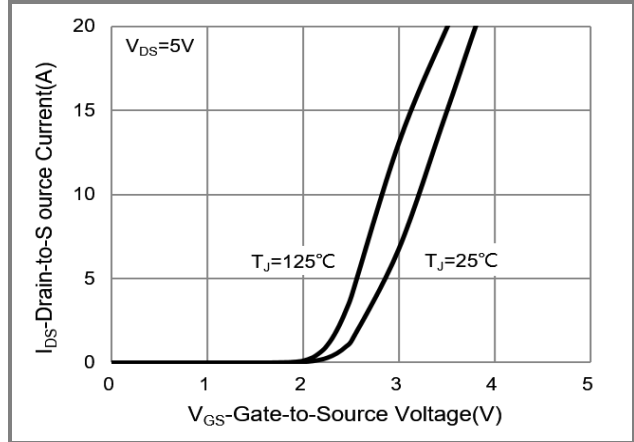


Fig.2 Transfer Characteristics

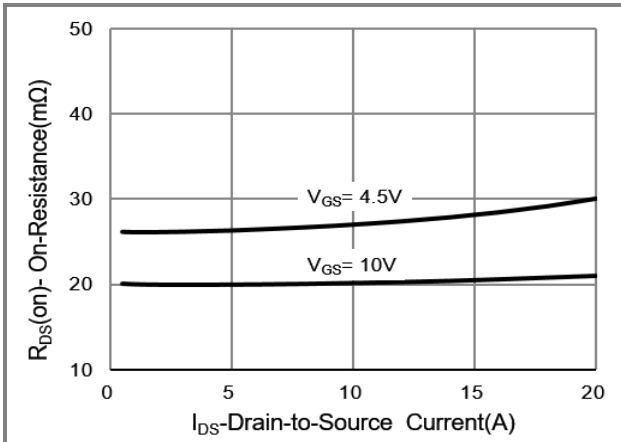


Fig.3 On-Resistance vs. Drain Current

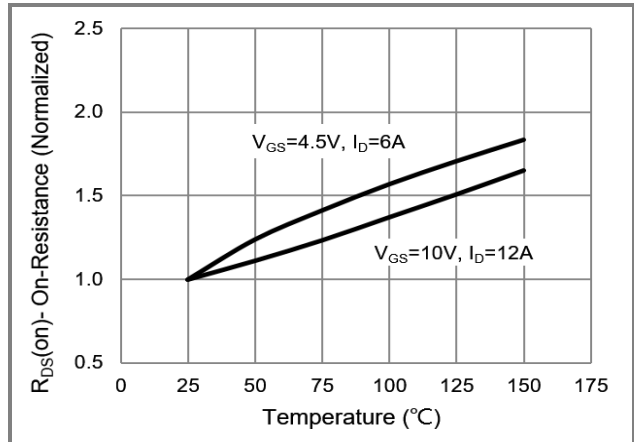


Fig.4 On-Resistance vs. Junction temperature

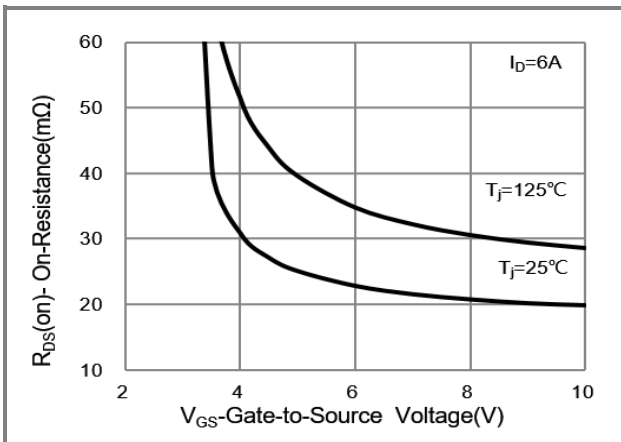


Fig.5 On-Resistance Variation with VGS.

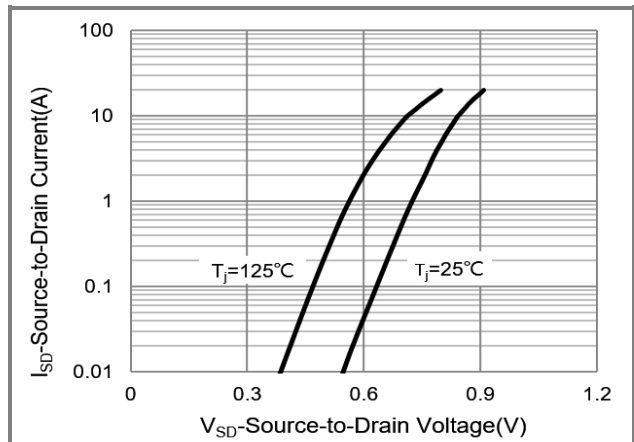


Fig.6 Source-Drain Diode Forward Voltage



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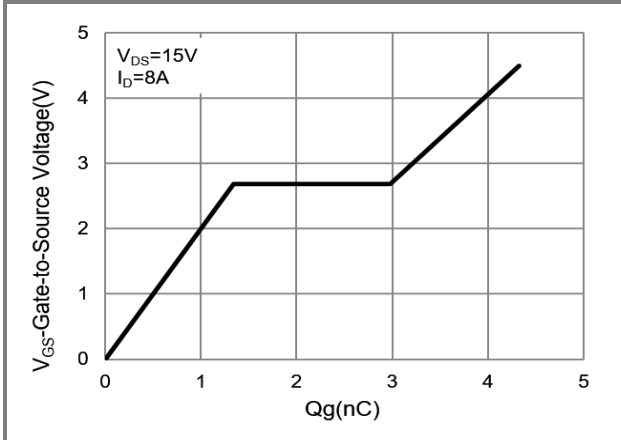


Fig.7 Gate-Charge Characteristics

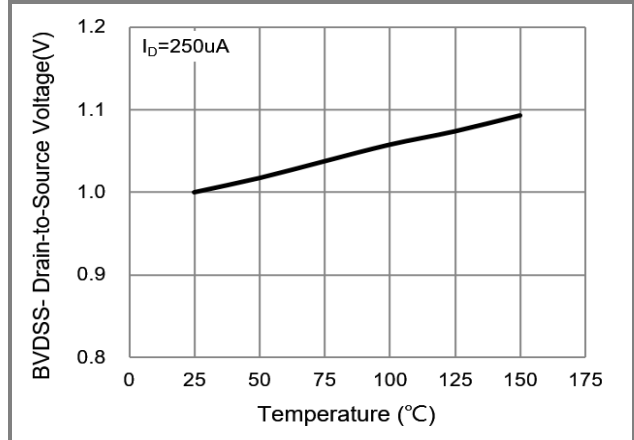


Fig.8 Breakdown Voltage Variation vs. Temperature

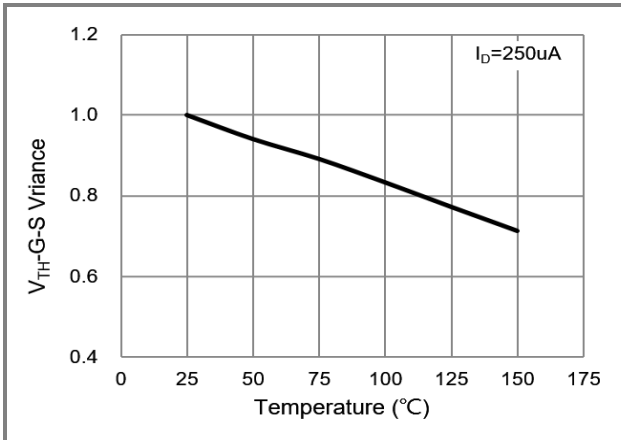


Fig.9 Threshold Voltage Variation with Temperature

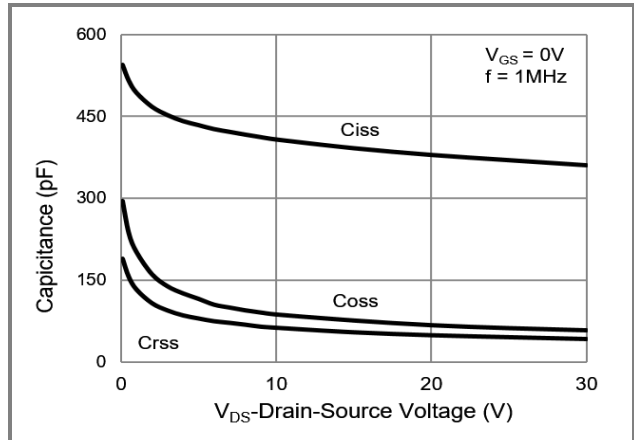


Fig.10 Capacitance vs. Drain-Source Voltage

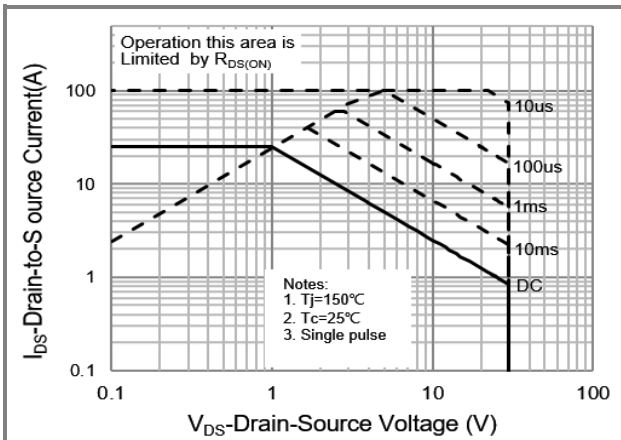


Fig.11 Maximum Safe Operating Area



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## TYPICAL CHARACTERISTIC CURVES

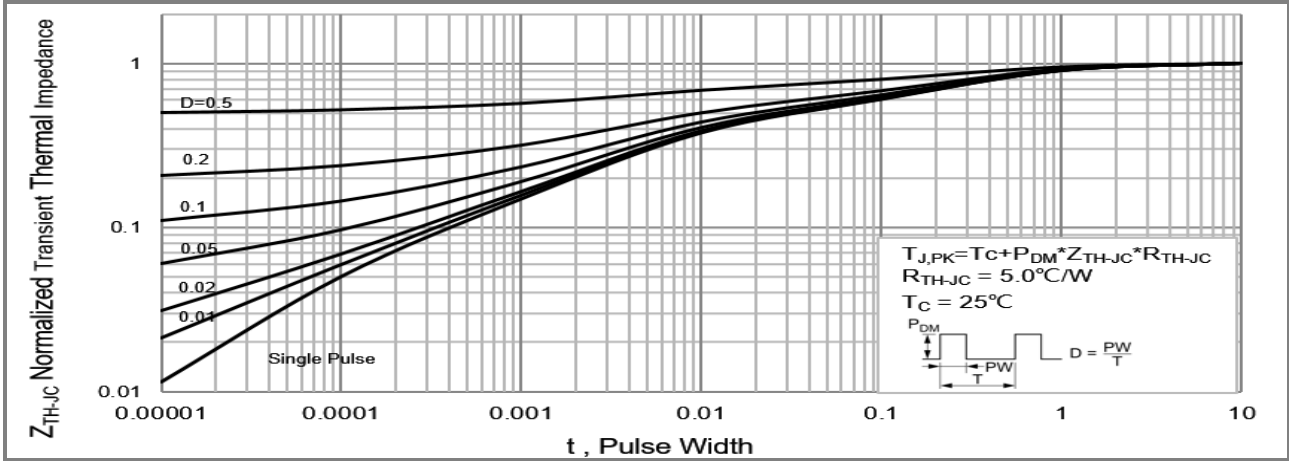
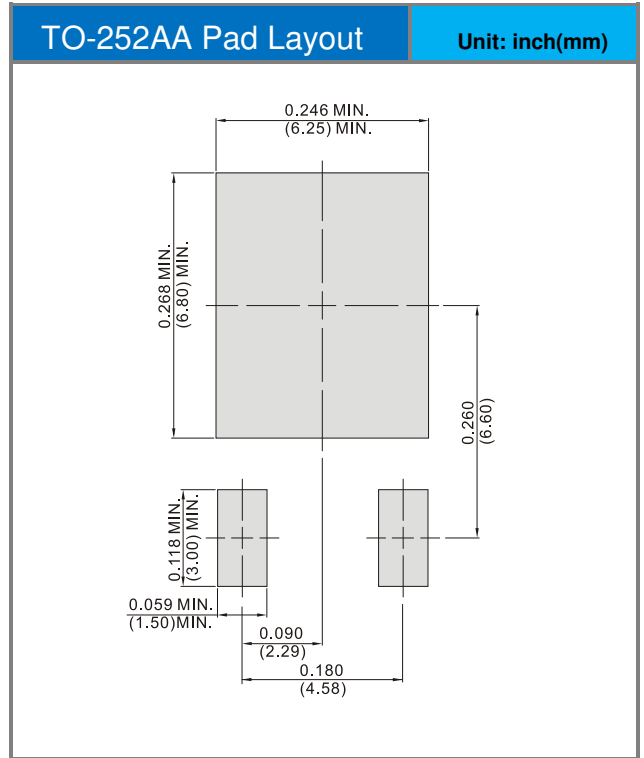
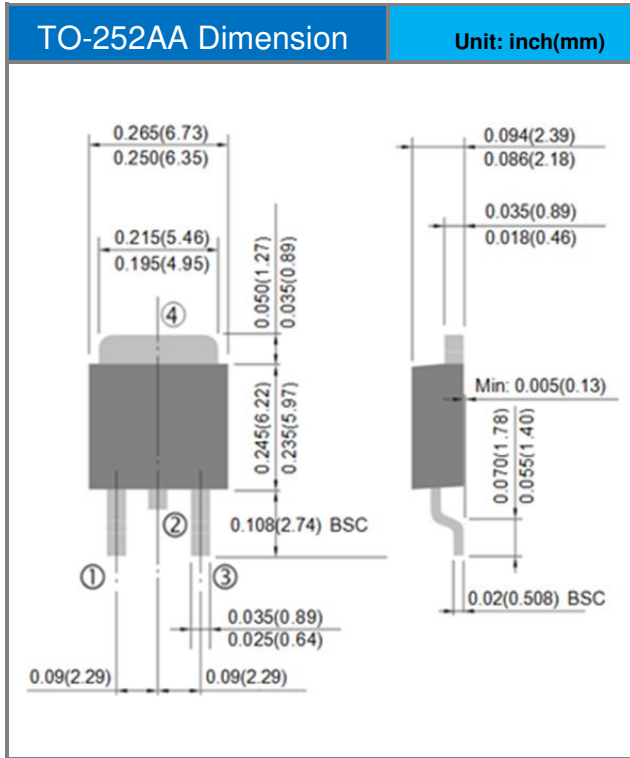


Fig.12 Normalized Transient Thermal Impedance vs. Pulse Width



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## Packaging Information & Mounting Pad Layout





# PJD25N03

## PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJD25N03_L2_00001	TO-252AA	3,000pcs / 13" reel	D25N03	Halogen free



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